

6MBI100VA-060-50

IGBT Modules

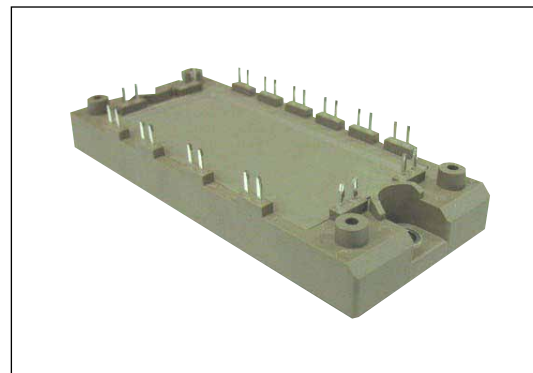
IGBT MODULE (V series) 600V / 100A / 6 in one package

■ Features

- Compact Package
- P.C.Board Mount
- Low $V_{CE(sat)}$

■ Applications

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply
- Industrial machines, such as welding machines



■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at $T_c=25^\circ\text{C}$ unless otherwise specified)

Items		Symbols	Conditions		Maximum ratings	Units
Inverter	Collector-Emitter voltage	V _{CES}			600	V
	Gate-Emitter voltage	V _{GES}			±20	V
	Collector current	I _c	Continuous	T _c =80°C	100	A
		I _{cp}	1ms	T _c =80°C	200	
		-I _c			100	
		-I _c pulse	1ms	200		
	Collector power dissipation	P _c	1 device	335	W	
Junction temperature		T _j			175	°C
Operating junciton temperature (under switching conditions)		T _{jop}			150	
Case temperature		T _c			125	
Storage temperature		T _{stg}			-40 to +125	
Isolation voltage	between terminal and copper base (*1) between thermistor and others (*2)	V _{iso}	AC : 1min.		2500	VAC
Screw torque	Mounting (*3)	-	M5		3.5	N m

Note *1: All terminals should be connected together during the test.

Note *2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

Note *3: Recommendable value : 2.5-3.5 Nm (M5)

● Electrical characteristics (at T_j = 25°C unless otherwise specified)

Items		Symbols	Conditions		Characteristics			Units
					min.	typ.	max.	
Inverter	Zero gate voltage collector current	I _{CES}	V _{GE} = 0V, V _{CE} = 600V		-	-	1.0	mA
	Gate-Emitter leakage current	I _{GES}	V _{GE} = 0V, V _{GE} = ±20V		-	-	200	nA
	Gate-Emitter threshold voltage	V _{GE (th)}	V _{CE} = 20V, I _C = 100mA		6.2	6.7	7.2	V
	Collector-Emitter saturation voltage	V _{CE (sat)} (terminal)	V _{GE} = 15V I _C = 100A	T _J =25°C	-	2.05	2.50	V
				T _J =125°C	-	2.35	-	
				T _J =150°C	-	2.55	-	
		V _{CE (sat)} (chip)	V _{GE} = 15V I _C = 100A	T _J =25°C	-	1.60	2.05	
				T _J =125°C	-	1.90	-	
				T _J =150°C	-	2.10	-	
	Internal gate resistance	R _{g(int)}	-		-	9	-	Ω
	Input capacitance	C _{ies}	V _{CE} = 10V, V _{GE} = 0V, f = 1MHz		-	6.4	-	nF
	Turn-on time	t _{on}	V _{CC} = 300V I _C = 100A V _{GE} = +15 / -15V R _G = 13Ω		-	0.36	1.20	μs
		t _r			-	0.25	0.60	
		t _{r (i)}			-	0.07	-	
	Turn-off time	t _{off}			-	0.52	1.20	
		t _f			-	0.03	0.45	
	Forward on voltage	V _F (terminal)	I _F = 100A	T _J =25°C	-	2.05	2.50	V
T _J =125°C				-	1.95	-		
T _J =150°C				-	1.90	-		
V _F (chip)		I _F = 100A	T _J =25°C	-	1.60	2.05		
			T _J =125°C	-	1.50	-		
			T _J =150°C	-	1.45	-		
Reverse recovery time	t _{rr}	I _F = 100A		-	-	0.35	μs	
Thermistor	Resistance	R	T = 25°C		-	5000	-	Ω
		T = 100°C		465	495	520		
	B value	B	T = 25 / 50°C		3305	3375	3450	K

● Thermal resistance characteristics

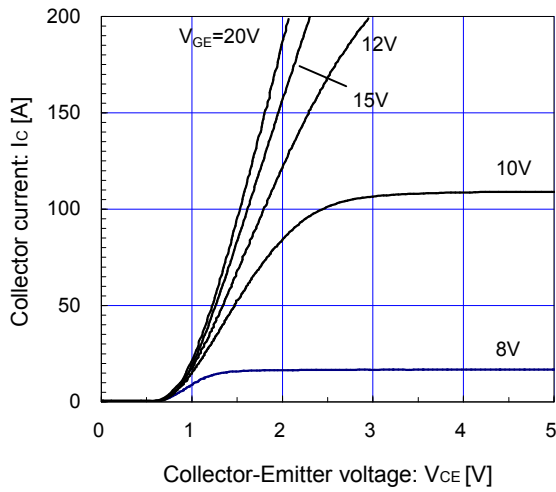
Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance (1device)	R _{th(j-c)}	Inverter IGBT	-	-	0.45	°C/W
		Inverter FWD	-	-	0.80	
Contact thermal resistance (1device) (*4)	R _{th(c-f)}	with Thermal Compound	-	0.05	-	

Note *4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Characteristics (Representative)

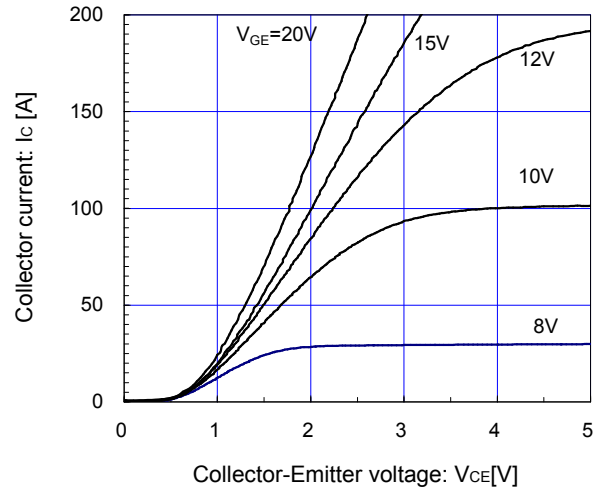
[Inverter]

Collector current vs. Collector-Emitter voltage (typ.)

 $T_j = 25^\circ\text{C}$ / chip

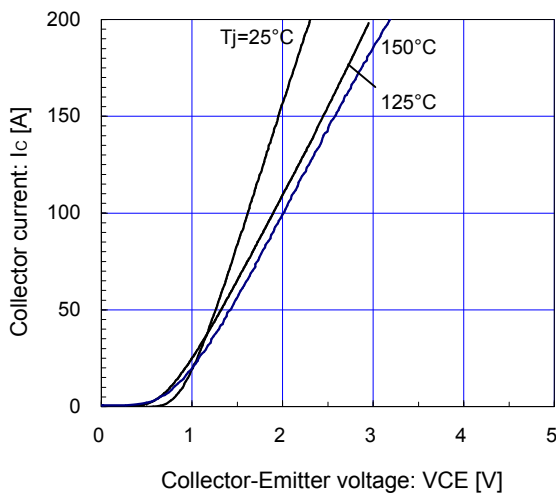
[Inverter]

Collector current vs. Collector-Emitter voltage (typ.)

 $T_j = 150^\circ\text{C}$ / chip

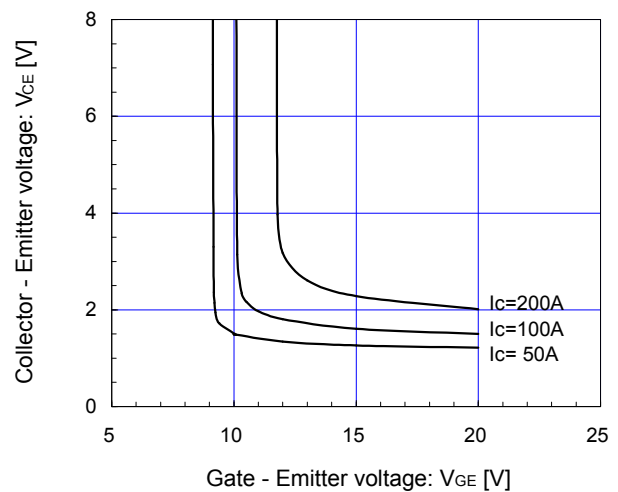
[Inverter]

Collector current vs. Collector-Emitter voltage (typ.)

 $V_{GE} = 15\text{V}$ / chip

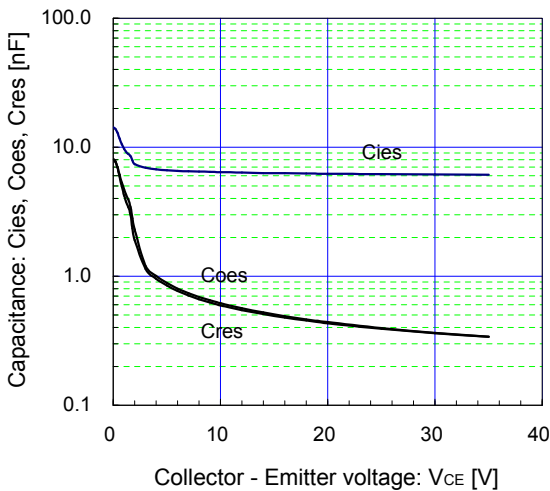
[Inverter]

Collector-Emitter voltage vs. Gate-Emitter voltage (typ.)

 $T_j = 25^\circ\text{C}$ / chip

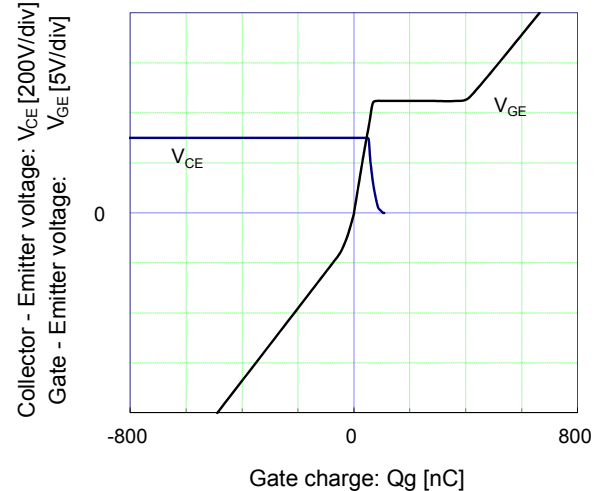
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Capacitance vs. Collector-Emitter voltage (typ.)

 $V_{GE} = 0\text{V}$, $f = 1\text{MHz}$, $T_j = 25^\circ\text{C}$ 

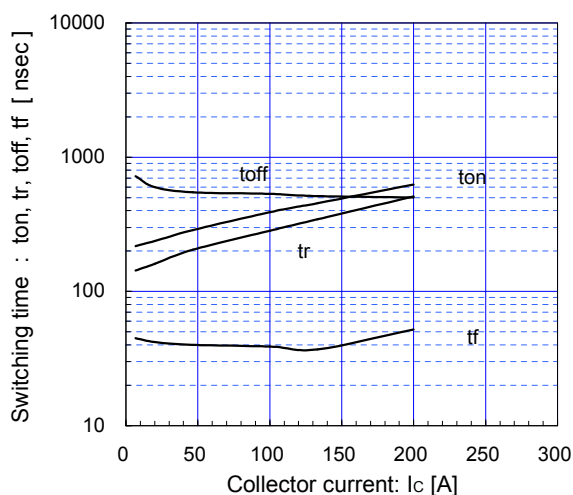
[Inverter]

Dynamic gate charge (typ.)

 $V_{CC} = 300\text{V}$, $I_C = 100\text{A}$, $T_j = 25^\circ\text{C}$ 

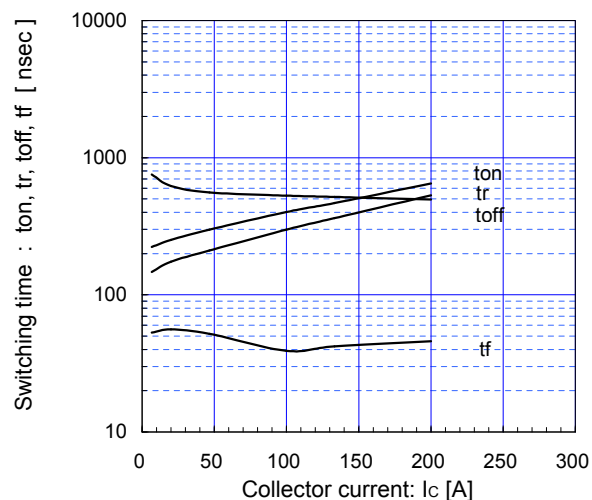
[Inverter]

Switching time vs. Collector current (typ.)
 $V_{CC}=300V$, $V_{GE}=\pm 15V$, $R_g=13\Omega$, $T_j=125^\circ C$



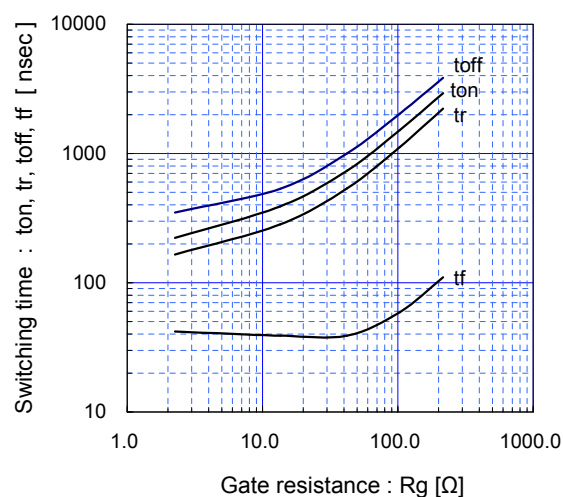
[Inverter]

Switching time vs. Collector current (typ.)
 $V_{CC}=300V$, $V_{GE}=\pm 15V$, $R_g=13\Omega$, $T_j=150^\circ C$



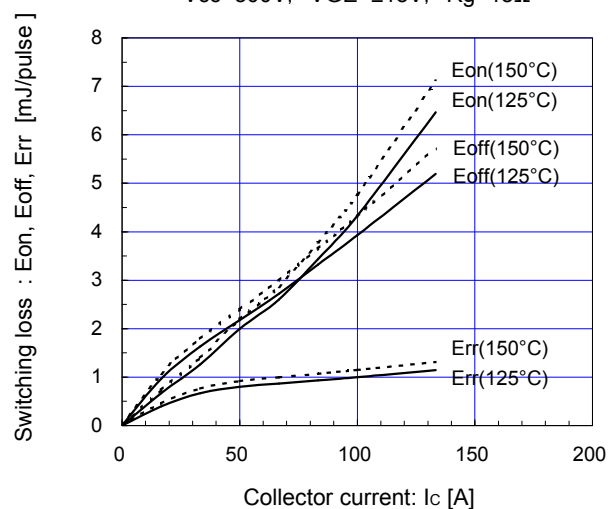
[Inverter]

Switching time vs. gate resistance (typ.)
 $V_{CC}=300V$, $I_c=100A$, $V_{GE}=\pm 15V$, $T_j=125^\circ C$



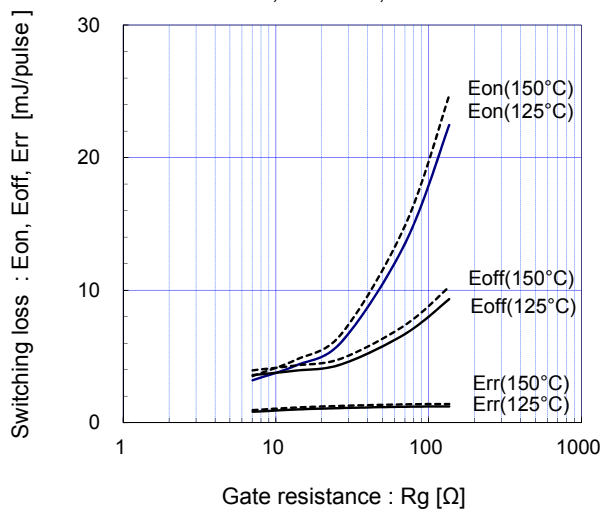
[Inverter]

Switching loss vs. Collector current (typ.)
 $V_{CC}=300V$, $V_{GE}=\pm 15V$, $R_g=13\Omega$



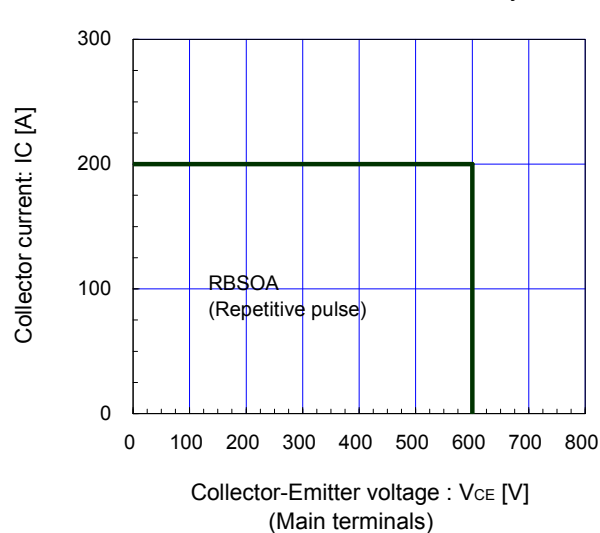
[Inverter]

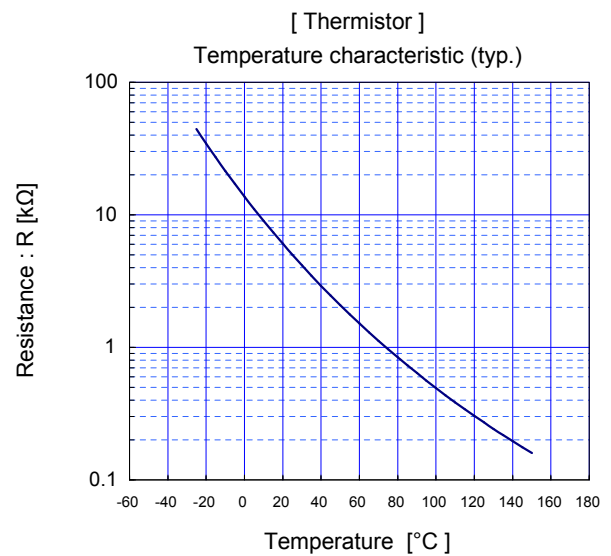
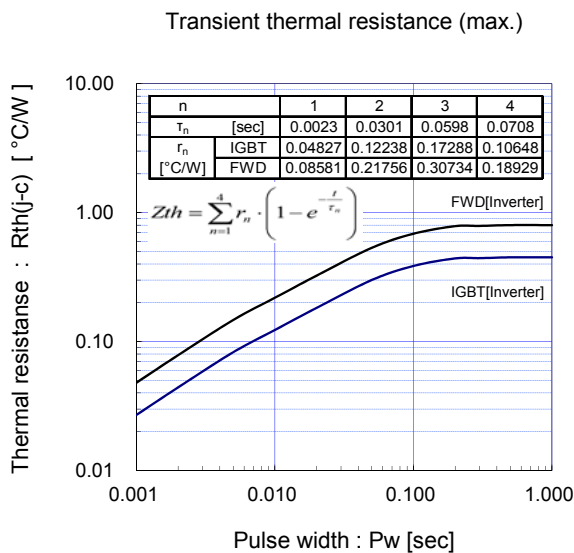
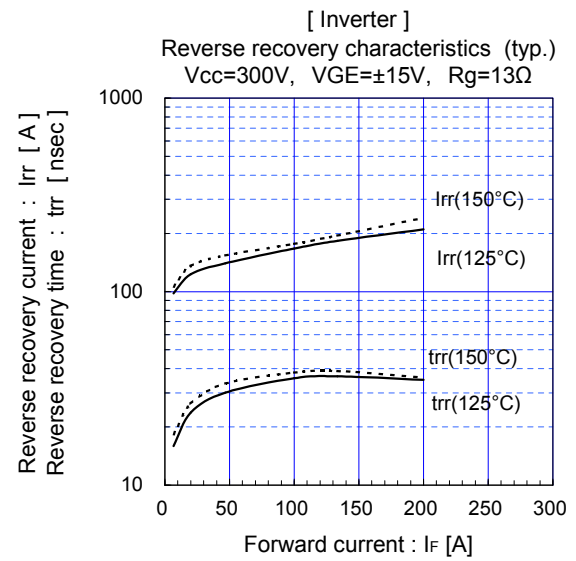
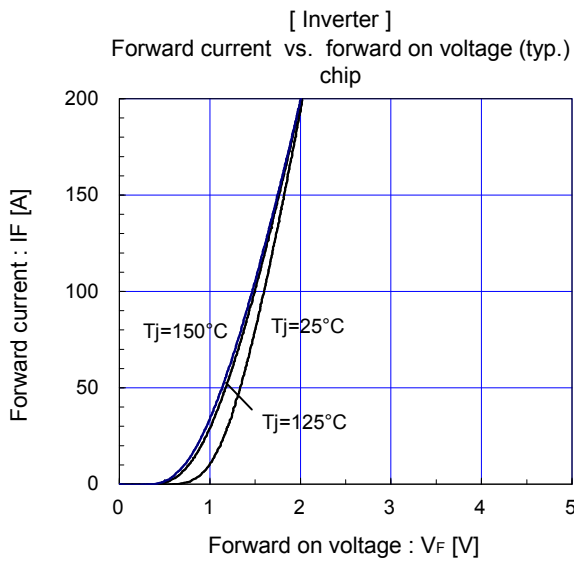
Switching loss vs. gate resistance (typ.)
 $V_{CC}=300V$, $I_c=100A$, $V_{GE}=\pm 15V$



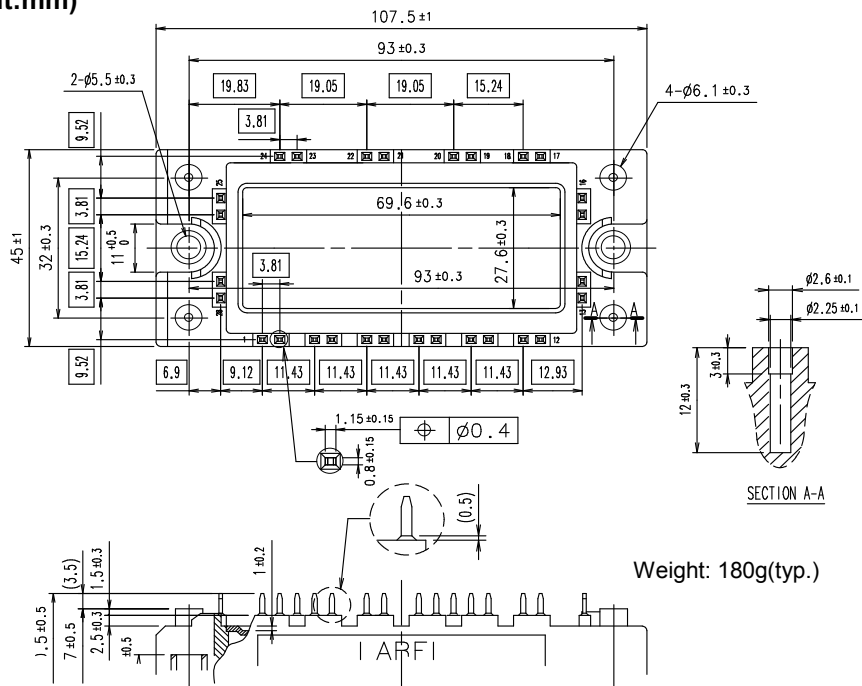
[Inverter]

Reverse bias safe operating area (max.)
 $+V_{GE}=15V$, $-V_{GE} \leq 15V$, $R_g \geq 13\Omega$, $T_j=150^\circ C$

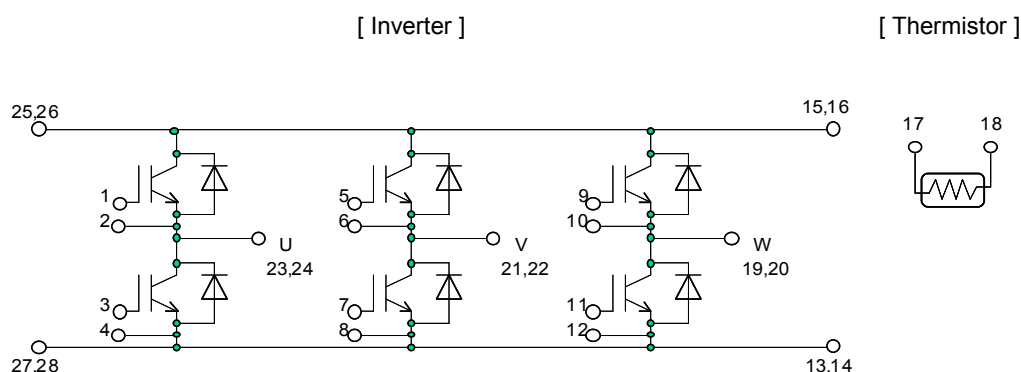




■ Outline Drawings(Unit:mm)



■ Equivalent Circuit



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